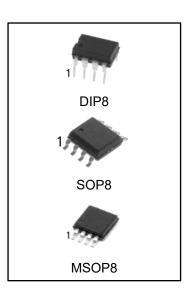


CMOS general purpose timer

Features

- Exact equivalent in most cases for SE/NE555.
- Low Supply Current.
- High speed operation 500 kHz guaranteed.
- Wide operation supply voltage range 2 to 18 volts.
- Timing from microseconds through hours.
- Operates in both astable and monostable modes.
- Adjustable duty cycle.
- High output source/sink driver can drive TTL/CMOS



Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
LMC555CN	DIP8	LMC555	TUBE	2000/box
LMC555CM/TR	SOP8	LMC555	REEL	2500/reel
LMC555CMM/TR	MSOP8	C555	REEL	3000/reel
LMC555IN	DIP8	LMC555	TUBE	2000/box
LMC555IM/TR	SOP8	LMC555	REEL	2500/reel
LMC555IMM/TR	MSOP8	C555	REEL	3000/reel

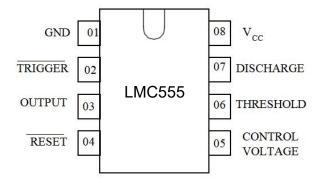


General Description

The LMC555 is CMOS RC timers providing significantly improved performance over the standard SE/NE555 and 355 timers, while at the same time being direct replacements for those devices in most applications. Improved parameters include low supply current, wide operating supply voltage range, low THRESHOLD, TRIGGER and RESET currents, no crowbarring of the supply current during output transitions, higher frequency performance and no requirement to decouple CONTROL VOLTAGE for stable operation.

Specifically, the LMC555 is stable controller capable of producing accurate time delays of frequencies.

PIN ASSIGNMENT



TRUTH TABLE

THRESHOLD	TRIGGER	RESET	OUTPUT	DISCHARGE
X	X	L	L	ON
> 2/3 V _{CC}	> 1/3 V _{CC}	Н	L	ON
< 2/3 V _{CC}	> 1/3 V _{CC}	Н	STABLE	STABLE
Х	< 1/3 V _{CC}	Н	Н	OFF



Maximum Ratings And Recommended Operating Conditions

Parameter, unit	Symbol	Recomm	onditions	Maximum ratings		
r ai ailletei, uillt	Symbol	Val	ue	Val	ue	
		min	max	min	max	
Supply Voltage, V	Vcc	2.0	18.0	0	18.0	
Output Current, mA	Io	-	20	-	100	
Input Voltage, V	VTH, VTRIG, VRST	-	-	-0.3	V _{CC} +0.3	
Power Dissipation, mW	P_D	-	-	-	200	
Operating Temperature,°C LMC555C	TOPR	0	70	0	70	
Operating Temperature,°C LMC555I	TOFIC	-40	85	-40	85	
Storage Temperature,°C	TSTG	-	-	-65	150	
Lead Temperature, 1 mm from Case for 10 Seconds,°C	TSOLDER	-	-		260	



DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

D	O h l	Test Condit	ions	Val	Tempe-		
Parameter, units	Symbol	IOL, IOH	VCC, B	min	max	rature, °C	
Throphold Voltage V	VTH		5.0	0.65 Vcc	0.70 Vcc	25±10	
Threshold Voltage, V	۷ΙΠ		5.0	0.60 V _{CC}	0.80 V _{CC}	-20, 70	
Trigger veltage V	VTRIG		5.0	0.31 V _{CC}	0.36 V _{CC}	25±10	
Trigger voltage, V	VIRIG		5.0	0.28 V _{CC}	0.40 V _{CC}	-20, 70	
			2.0	0.4	1.0	25±10	
Poset voltage V	VRST		18.0	0.4	1.0	25±10	
Reset voltage, V	VKSI		2.0	0.2	1.5	20. 70	
			18.0	0.2	1.5	-20, 70	
Control Voltage Lead, V	VCV			0.65 V _{CC}	0.69 V _{CC}	25 10	
Control voltage Lead, v	VCV			0.60 V _{CC}	0.80 V _{CC}	-20, 70	
	VoL	I _{OL} = 3.2 mA	5.0		0.4	25 40	
Output voltage Low, V		I _{OL} = 20 mA	15.0		1.0	25±10	
Output voltage Low, v		I _{OL} = 3.2 mA	5.0		0.6	20. 70	
		I _{OL} = 20 mA	15.0		1.5	-20, 70	
			5.0	4.0		25±10	
Output voltage High, V	Voн	I _{OH} = -0.8 mA	15.0	14.3		25±10	
Output voitage High, v	۷ОП	10H0.6 IIIA	5.0	3.5		20. 70	
			15.0	14.0		-20, 70	
Committee Committee of			2.0		200	25 \(\pm 10	
	ICC		18.0		300	25±10	
Supply Current, μA	100		2.0		400	20. 70	
			18.0		600	-20, 70	



AC ELECTRICAL CHARACTERISTICS

		Test Conditions		Va	Tempe-	
Parameter, unit	Symbol	R _L , C _L	VCC, V	Min	Max	rature, °C
Rise (Fall) Time of	tTHL,	$R_L = 10 \text{ M}$, $C_L = 10 \text{ pF}$	5.0	35	75	25±10
Output,ns	tTLH	, - ,		70	150	-20, 70
Guaranteed Max	fMAX	Astable Operation	2.0-	500		25±10
Osc Freq,kHz		'	18.0	200		-20, 70
Initial accuracy, %				5		
Drift with Tomporature			5.0		0.02	
Drift with Temperature, %/°C	f	R∟ = 1 - 100 k	10.0		0.03	-20, 70
		C∟= 0.1 µF	15.0		0.06	
Drift with Supply Voltage,	£		F 0		3	25±10
%/B	I		5.0		6	-20, 70

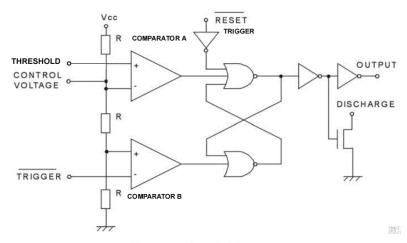


Figura 1. Block Diagram

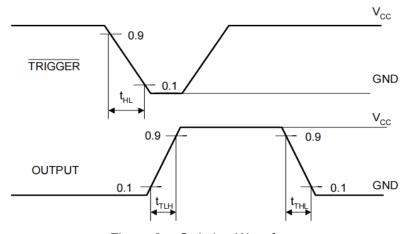
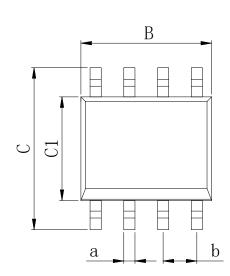


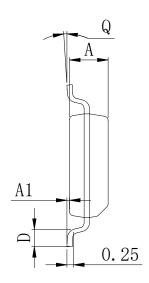
Figura 2. Switcing Waveforms



Physical Dimensions

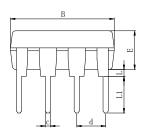
SOP8



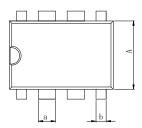


Dimensions In Millimeters(SOP8)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.27 650

DIP8





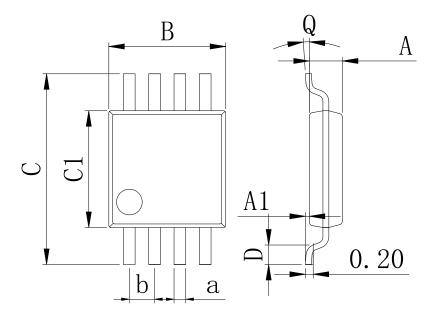


Dimensions In Millimeters(DIP8)											
Symbol:	Α	В	D	D1	Е	L	L1	а	b	С	р
Min:	6.10	9.00	8.40	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2 E4 BSC
Max:	6.68	9.50	9.00	7.82	3.55	0.70	3.60	1.55	0.90	0.50	2.54 BSC



Physical Dimensions

MSOP8



Dimensions In Millimeters(MSOP8)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	0.00 650



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